TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSVI)

# **TPC8128**

### Lithium Ion Battery Applications Power Management Switch Applications

- Small footprint due to small and thin package
- Low drain-source ON-resistance:  $R_{DS}$  (ON) = 3.9 m $\Omega$  (typ.)
- Low leakage current:  $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -30 \ V)$
- Enhancement mode:  $V_{th}$  = -0.8 to -2.0 V ( $V_{DS}$  = -10 V,  $I_D$  = -0.5mA)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteri	stics	Symbol	Rating	Unit	
Drain-source voltage		V <sub>DSS</sub>	-30	V	
Drain-gate voltage (R	<sub>GS</sub> = 20 kΩ)	V <sub>DGR</sub>	-30	V	
Gate-source voltage		V <sub>GSS</sub>	-25/+20	V	
Drain current	DC (Note 1)	Ι <sub>D</sub>	-16	А	
Dialiteuren	Pulse (Note 1)	I <sub>DP</sub>	-64	~	
Drain power dissipatio	n (t = 10 s) (Note 2a)	PD	1.9	W	
Drain power dissipatio	n (t = 10 s) (Note 2b)	PD	1.0	W	
Single pulse avalanch	e energy (Note 3)	E <sub>AS</sub>	166	mJ	
Avalanche current	(Note 1)	I <sub>AR</sub>	-16	А	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature r	ange	T <sub>stg</sub>	-55 to 150	°C	

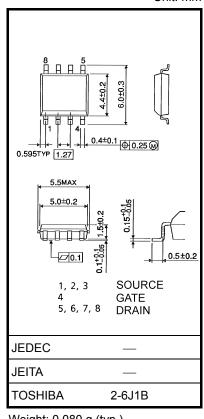
Note 1, Note 2, Note 3 : See the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating

temperature/current/voltage, etc.) are within the absolute maximum ratings.

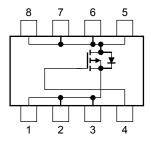
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.080 g (typ.)

## **Circuit Configuration**



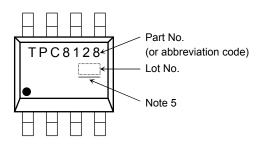
Unit: mm

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## Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient $(t = 10 s)$ (Note 2a)	R <sub>th (ch-a)</sub>	65.8	°C/W
Thermal resistance, channel to ambient $(t = 10 s)$ (Note 2b)	R <sub>th (ch-a)</sub>	125	°C/W

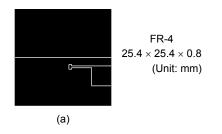
## Marking (Note 4)

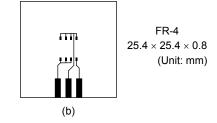


Note 1: Ensure that the channel temperature does not exceed 150  $^{\circ}\text{C}.$ 

Note 2: (a)Device mounted on a glass-epoxy board (a)

(b)Device mounted on a glass-epoxy board (b)





Note 3:  $V_{DD} = -24$  V,  $T_{ch} = 25$  °C (initial), L = 500  $\mu$ H, R<sub>G</sub> = 25  $\Omega$ , I<sub>AR</sub> = -16 A



Week of manufacture (01 for the first week of a year: sequential number up to 52 or 53) Year of manufacture (The last digit of a year)

Note 5: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Electrical Characteristics (Ta = 25°C)

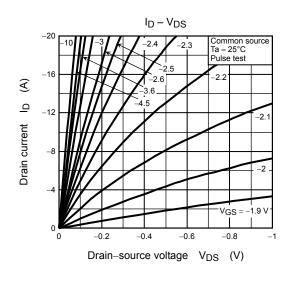
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curre	ent	I <sub>GSS</sub>	$V_{GS}=\pm 20~V,~V_{DS}=0~V$	_	_	±100	nA
Drain cut-OFF cur	rent	I <sub>DSS</sub>	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_	—	-10	μA
Drain agurag brag	n cut-OFF current n-source breakdown voltage threshold voltage n-source ON-resistance t capacitance erse transfer capacitance out capacitance Rise time Turn-ON time	V (BR) DSS	$I_{D} = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-30		_	V
Drain-source brea	Kuown voltage	V (BR) DSX	$I_D = -10 \text{ mA}, V_{GS} = 10 \text{ V}$ (Note 6)	10         -30          -21          -0.8      2.0          5.3         6.9          3.9         5       -         4800	v		
Gate threshold vol	tage			_	-2.0	V	
Drain source ON r			$V_{GS}=-4.5 \text{ V}, \text{ I}_{D}=-8 \text{ A}$	_	5.3	6.9	mΩ
Input capacitance		rds (ON)	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -8 \text{ A}$	_	3.9	5	
Input capacitance		C <sub>iss</sub>	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	4800	_	pF
Reverse transfer capacitance		C <sub>rss</sub>		_	800	_	
Output capacitance		C <sub>oss</sub>		—	900		
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Rise time	tr	$V_{CS} = \frac{0}{1} \nabla_{T} = -8 A$		10		
	19		ns				
	Fall time	t <sub>f</sub>			140		. 115
	Turn-OFF time			_	420		
		Qg	Vpp≈-24 V Vcs=-10 V		115		nC
Gate-source charge 1		Q <sub>gs1</sub>	$I_{\rm D} = -16  {\rm A}$	—	11	_	
Gate-drain ("miller	") charge	Q <sub>gd</sub>		—	30	_	

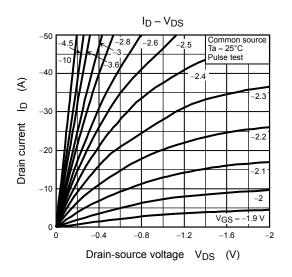
## Source-Drain Ratings and Characteristics (Ta = 25°C)

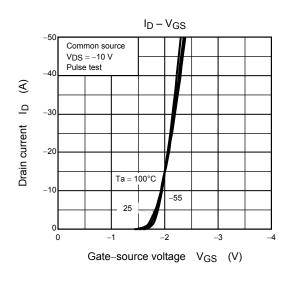
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	I <sub>DRP</sub>	_	_	_	-64	А
Forward voltage (diode)		V <sub>DSF</sub>	I <sub>DR</sub> = -16 A, V <sub>GS</sub> = 0 V			1.2	V	

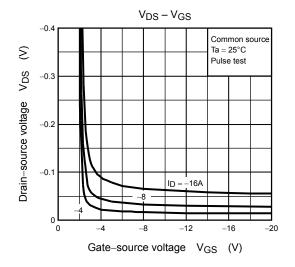
Note 6: VDSX mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.

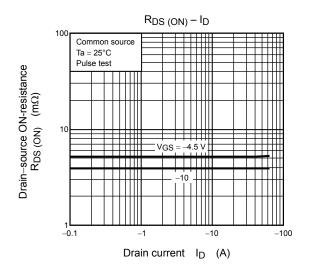
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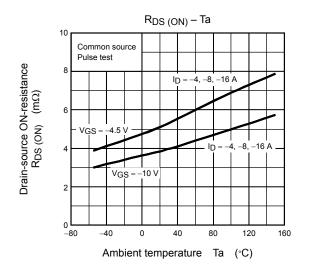


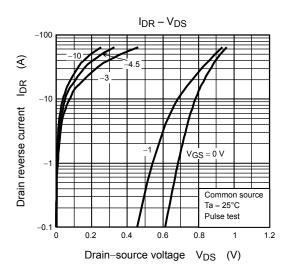


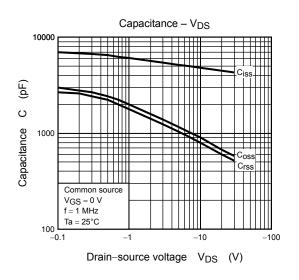


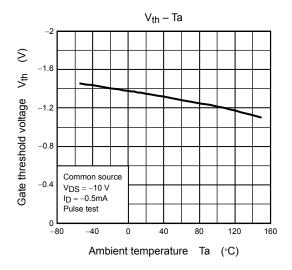


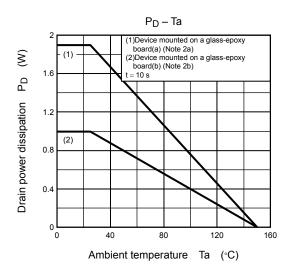
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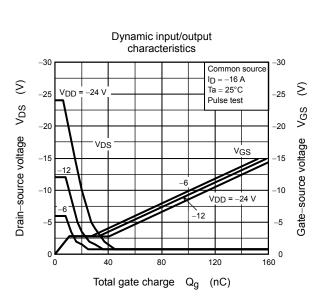


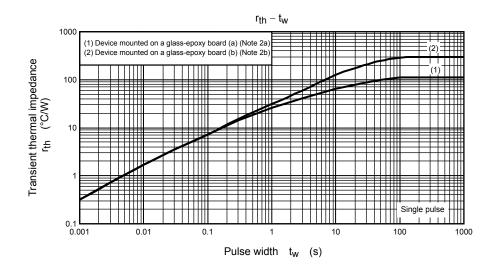


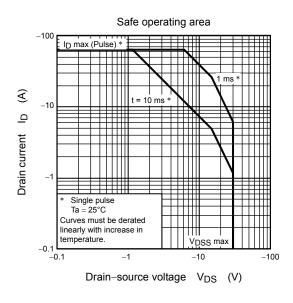












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